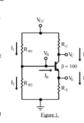
Problem Set 3 (Again)

October 30, 2017 10:57 AM

2) For the circuit shown in figure 1, use the $1/3^{st}$ rule with $V_L = V_{CC}/3$ to find R_{El} , R_{El} , R_{Cl} , and I_{Cl} given that $R_C = 84\Omega$ and $V_{CC} = 12V$. (Answers: $R_{El} = 1464\Omega$, $R_{El} = 1044\Omega$, $R_{El} = 1044\Omega$, and $I_{Cl} = 1044\Omega$).

3) What are g_{∞} and r_{π} for the transistors in P1 and P2

5) Assuming that a small-signal a.c. voltage source with a 500 source impedance is coupled to the amplifier of P? 300 source impedance is coupled to the amplifier of P? 300 voltage squested and that R_c is high passed using a 50µ° coposition and that the hybrid-impedal has the following parameters: f_n = [0.0]_N = 2.9°, and f_n = 0... what are A_N , ω_{MM}, and ω_{MM} ? A_N = 1.8°, ω_{MM}, and ω_{MM} ? A_N = 1.8°, ω_{MM}, and ω_{MM} ? ω_{MM} = 4.0°, and α_{MM} = 4.4°, and γ ω_{MM} = 4.4°, and γ ω_{MM}



Q2: Second /3 rule: VE=1/3 Va. Vo=2/3 Vac, I = 1/8

Glver-z Vcc=121, R==8152

VE=4V , Vc=8V , VR=4.7V

 $I_{E} = \frac{VE}{Rc} = \frac{4V}{8k\Omega} = 0.500 \text{ mA}$

IN= 17B IE = 101 (0.500MA)= 4.95 MA

Ic= PIB= 0.445WA

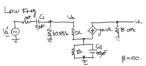
121-81 = 3c, Re = 121-81 = 120-81 = 18.08KD

II= JE = 0.5MA = 50MA

Vcc - Ve = I1, Re1 = 12V-4.7V = 146K/2

I== I1- IB = 45.05/A

VB = I2, RB2 = Ub = 4.7V = 104.33k2



- SCTC test: -. VSL = (50+ (6085K 1/5K)). 10g/F = 47ms. X TE = [(50/160 85k +5k)(+p) // 8k]. 50ut = 2.484 ms.

Tac = [50+60 85K/1(5K+(1+P/(8K))].10/1F = 0.5675

Wep= 402.6 mad/, Wep==1.764 rad/s

WLZZ= Q. STUF = 7.5 rad/s

Wisds= (Wep2+ Wep2-2Wez? -2Wez?) = (402.6 rad/s.)

F(6) = (S+25) S+1.764)

Q1. First 1/3 rule: V==3kc, V==3kc. I== Vu =(5V, Tc=2mA

Ve= 3/4 le = 10V, Ve= \$160= 5V, Ve = Ve-0.7 = 4.3V

Ice Vec-Ve , Re= Vec-Ve = 5V = 2.5KD

IB= = TC = TO 2MA = 201A

J5=Jc+I8 = 2.02mA

RE = VE = 43V = 2.10KD

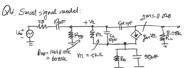
 $I = \frac{J_E}{\sqrt{r}} = \frac{2.02 \text{mA}}{\sqrt{100}} = 202 \text{mA}$

VC-VB = J1, RBIE VCC-VB = 15-5 = 49.5K2

J2= J1- In= 182/1A

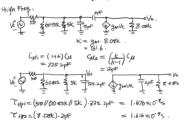
VB = I2 , RB2 = VB = 27,47KA





10-1 D REPOSSE SEK Dank \$8.98

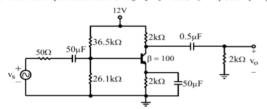
Va= -guva.(8.08K) =-(0.020)(0.989)Vs.(B.08K) = 0.92945 Vo = -159.822 = Am.

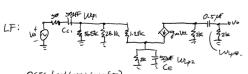


THOUBE THOUTHY WHOUB = 42.95 Mood/s.

FH(57= (60M) 62M S+62M)

5) For the circuit shown in figure 2: i. Draw the low frequency circuit, the midband circuit and the high frequency circuit and ii. Derive the complete transfer function using $~I_{z}^{~}\approx I_{c}^{~}=2$ mA, $~c_{\pi}^{~}=1$ 0pF, and $~c_{\mu}^{~}=2$ pF.





OCTC test (want (over frey) (a = 50/1F(50+365K1/26.1K//(1.25K+(1+β)2K))=0.7105 $T_{00}^{CE} = 50 \mu F \cdot ((76 \text{ sk} 1/26.1 \text{ k}) + 1.25 \text{ k}) (\frac{1}{(Hp)}) 1/2 \text{ k}) = 0.0085 \times 10^{-10}$

To = SUM TU...

SCTC test

The SUM [((50 // 16.5K // 26.1K) + (1.25K)) (1+p) // 24]= 1.639MS.

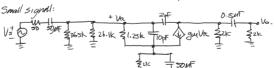
Wes=Weg=0 valls

WLps = 1619.6 rad/s

WC2= 2k.50# = 10rad/s

1.11 - 1110 n-1511- - 11

Brasing IEXIC=2mA, Iz= 20MA gu= Te = 2mA = 0.080. Mr. = = 1.25ks. VE= 4V. -> V8-4.7V. JI=200NA, JZ=120NA



Am Bt Vr= (36.5K/1 26.1K/1 1.25K) .Vs (36.5L11 26.1K//12.5k)+50 = 0.959 V .

Vb = -gm Vn·lk = -(0.080)(1 k)(0.959) Vs b = - 76.681

K= gm.1k = 0.08(14) = 80.

-> Cal= 162 pF, Can=2pF

= 2×10-95

THPI = (10pF+162pF). [50//36.5k//26.1k//1.25k]

= 8.243×10-95 Ellp2 = (2pF)(1K) WHP1 = 121.3Mrad/s WGpz = 500Mradis

FH(5)= (117.7M) 500M S+ 500M

Wepi = 1:408 radls Wlps = 1619.6 radls

WL93= (HK. 0.5MF)"=500 rad/s

Wes=Wes=0 rad/s lb=[-76.68] WC22= 12k.504 = 10rad/s

= -(0.080)(1 K)(0.959)Vs

 $= 2 \times 10^{-4}$

WGpz = 500Mradis

FH(5)= (117.7M) (500M) (5+ 300M)

FL = (5 | S+ 10) (5 | S+ 500) (5 | S+ 500)